

TRANSMIT/RECEIVE SWITCH

RoHS Compliant & Pb-Free Product

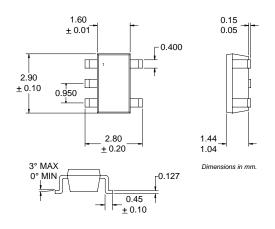
Typical Applications

- Cordless Phones
- Wireless Computer Peripherals
- Wireless Security Systems

- General Purpose RF Switching
- Commercial and Consumer Systems

Product Description

The RF2436 is a very low-cost transmit/receive GaAs MESFET switch. The device can handle power levels as high as +28dBm and spans a frequency range from DC to 2500MHz. The switch will operate from power supply voltages as low as 1.5V and as high as 6V with a CMOS logic driver for the control input. No negative voltage is required, and current consumption is very low. VSWR for the active channel (transmit or receive) is 1.1:1. The device is housed in a very small industry-standard SOT 5-lead plastic package.



Optimum Technology Matching® Applied

- ☐ Si BJT ☐ GaAs HBT ☑ GaAs MESFET☐ Si Bi-CMOS☐ SiGe HBT ☐ Si CMOS☐ InGaP/HBT☐ GaN HEMT☐ SiGe Bi-CMOS☐
 - RX OUT 1 5 ANT I/O
 GND 2 4 TX/RX

Functional Block Diagram

Package Style: SOT-5

Features

- Single Positive Power Supply
- Low Current Consumption
- 1dB Insertion Loss at 900MHz
- 24dB Crosstalk Isolation at 900MHz
- +27dBm Output P1dB

Ordering Information

RF2436 Transmit/Receive Switch
RF2436 PCBA Fully Assembled Evaluation Board

 RF Micro Devices, Inc.
 Tel (336) 664 1233

 7628 Thorndike Road
 Fax (336) 664 0454

 Greensboro, NC 27409, USA
 http://www.rfmd.com

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RF2436

Absolute Maximum Ratings

Parameter	Rating	Unit			
Supply Voltage	0 to +8.0	V_{DC}			
Control Voltage	-1.0 to +6.0	V			
Input RF Power	+30	dBm			
Operating Ambient Temperature	-40 to +85	°C			
Storage Temperature	-40 to +150	°C			



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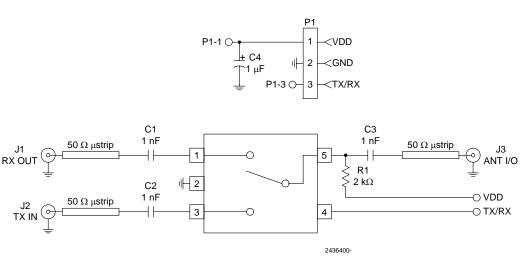
Parameter	Specification		Unit	Condition		
Farameter	Min.	Тур.	Max.	Offic	Condition	
Overall					T=25 °C, V _{DD} =3.0 V, Freq=900MHz	
Frequency Range		DC to 2500		MHz		
Insertion Loss		1	2	dB	Transmit or receive mode.	
Isolation	20	22		dB	Receive mode; ANT I/O to TX IN crosstalk	
	20	24		dB	Transmit mode; ANT I/O to RXOUT crosstalk	
RX OUT VSWR		1.1:1			Receive mode.	
TX IN VSWR		1.1:1			Transmit mode.	
Output P1dB		+27		dBm		
Output IP3		+39		dBm		
Control Logic						
CTRL Logic "Low" Voltage		0		V	Receive mode.	
CTRL Logic "High" Voltage		0.7		V	Transmit mode.	
Power Supply						
Voltage		3		V	Specifications	
_		1.5 to 6		V	Operating Limits	
Current		5	10	μΑ	Receive mode.	
		0.5	1	mA	Transmit mode.	

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Pin	Function	Description	Interface Schematic
1	RX OUT	Output pin for Receive mode. VSWR is 1.1:1 when Receive mode is selected and highly capacitive when Transmit mode is selected.	
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to the ground plane.	
3	TX IN	Input pin for Transmit mode. The input VSWR is 1.1:1 when Transmit mode is selected and highly capacitive when Receive mode is selected.	
4	TX/RX	Transmit Mode/Receive Mode control pin. A "low" level chooses Receive mode; a "high" level chooses Transmit mode. CMOS logic may be used to drive the control input.	
5	ANT I/O	Input/Output pin from/to antenna and power supply pin. This pin must be biased with VDD through a resistor.	

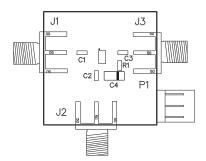
Evaluation Board Schematic

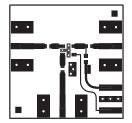
(Download Bill of Materials from www.rfmd.com.)



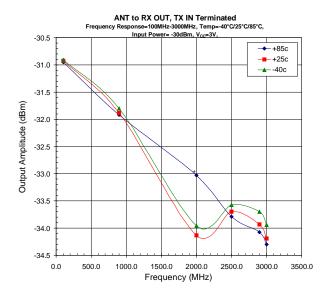
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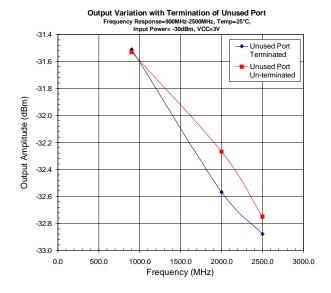
Evaluation Board Layout





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